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INFORMATION DISCLOSURE STATEMENT BY APPLICANT	Applicant Doo Hyeb YOUN et al	
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[illegible][illegible]

LP		'Observation of the Mott Transition in VO ₂ Based Transistors', Kim, Hyun-Tak, et al. Telecom. Basic Research Lab, ETRI, Daejeon 305-350, South Korea (August 2, 2003) pp.1-4.
↓		'Gate-Induced Mott Transition'. Kim, Hyun-Tak, et al. Telecom. Basic Research Lab, ETRI, Daejeon 305-350, Korea (May 27, 2003) pp. 1-4.
EXAMINER	L. PHAM	DATE CONSIDERED 5/31/07
EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		

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